Preferred Device

### **Sensitive Gate Triacs**

## **Silicon Bidirectional Thyristors**

Designed for use in solid state relays, MPU interface, TTL logic and any other light industrial or consumer application. Supplied in an inexpensive TO-92 package which is readily adaptable for use in automatic insertion equipment.

- One-Piece, Injection-Molded Package
- Blocking Voltage to 600 Volts
- Sensitive Gate Triggering in Four Trigger Modes (Quadrants) for all possible Combinations of Trigger Sources, and especially for Circuits that Source Gate Drives
- All Diffused and Glassivated Junctions for Maximum Uniformity of Parameters and Reliability
- Device Marking: Device Type, e.g., MAC97A4, Date Code

#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

| Rating  | Symbol                                 | Value             | Unit             |
|---|--|-------------------|------------------|
| Peak Repetitive Off-State Voltage (T <sub>J</sub> = -40 to +110°C) (Note 1) Sine Wave 50 to 60 Hz, Gate Open MAC97A4 MAC97A6 MAC97-8, MAC97A8 | V <sub>DRM</sub> ,<br>V <sub>RRM</sub> | 200<br>400<br>600 | Volts            |
| On-State RMS Current Full Cycle Sine Wave 50 to 60 Hz (T <sub>C</sub> = +50°C)  | I <sub>T(RMS)</sub>                    | 0.6               | Amp              |
| Peak Non–Repetitive Surge Current<br>One Full Cycle, Sine Wave 60 Hz<br>$(T_C = 110$ °C)  | I <sub>TSM</sub>                       | 8.0               | Amps             |
| Circuit Fusing Considerations (t = 8.3 ms)  | l <sup>2</sup> t                       | 0.26              | A <sup>2</sup> s |
| Peak Gate Voltage<br>(t $\leq 2.0 \mu s$ , T <sub>C</sub> = +80°C)  | V <sub>GM</sub>                        | 5.0               | Volts            |
| Peak Gate Power (t $\leq 2.0 \mu\text{s},  T_{\text{C}} = +80^{\circ}\text{C}$ )  | $P_{GM}$                               | 5.0               | Watts            |
| Average Gate Power $(T_C = 80^{\circ}C, t \le 8.3 \text{ ms})$  | P <sub>G(AV)</sub>                     | 0.1               | Watt             |
| Peak Gate Current<br>(t $\leq 2.0 \mu s$ , T <sub>C</sub> = +80°C)  | I <sub>GM</sub>                        | 1.0               | Amp              |
| Operating Junction Temperature Range  | TJ                                     | -40 to +110       | °C               |
| Storage Temperature Range   | T <sub>stg</sub>                       | -40 to +150       | °C               |

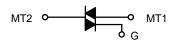
V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

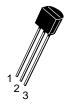


#### ON Semiconductor®

http://onsemi.com

# TRIACS 0.8 AMPERE RMS 200 thru 600 VOLTS





TO-92 (TO-226AA) CASE 029 STYLE 12

| PIN ASSIGNMENT |                 |  |  |
|----------------|-----------------|--|--|
| 1              | Main Terminal 1 |  |  |
| 2              | Gate            |  |  |
| 3              | Main Terminal 2 |  |  |

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

#### THERMAL CHARACTERISTICS

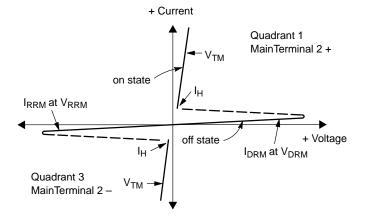
| Characteristic   | Symbol          | Max | Unit |
|--|-----------------|-----|------|
| Thermal Resistance, Junction to Case                           | $R_{\theta JC}$ | 75  | °C/W |
| Thermal Resistance, Junction to Ambient                        | $R_{\theta JA}$ | 200 | °C/W |
| Maximum Lead Temperature for Soldering Purposes for 10 Seconds | TL              | 260 | °C   |

#### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions)

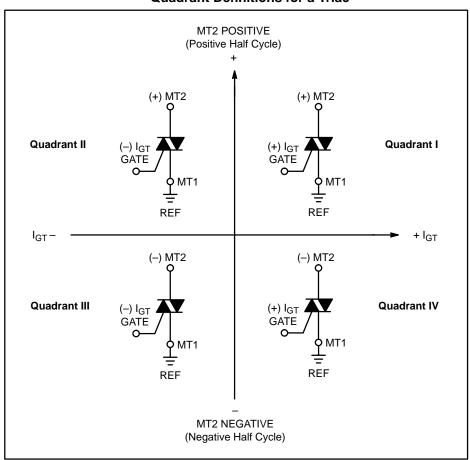
| Characteristic  | Symbol                              | Min              | Тур                      | Max                      | Unit                     |
|---|-------------------------------------|------------------|--------------------------|--------------------------|--------------------------|
| OFF CHARACTERISTICS   |                                     | •                |                          | •                        | •                        |
| Peak Repetitive Blocking Current ( $V_D$ = Rated $V_{DRM}$ , $V_{RRM}$ ; Gate Open) $T_J = 25^{\circ}C$ $T_J = +110^{\circ}C$   | I <sub>DRM</sub> , I <sub>RRM</sub> | -<br>-           | _<br>_                   | 10<br>100                | μ <b>Α</b><br>μ <b>Α</b> |
| ON CHARACTERISTICS  |                                     | •                |                          | •                        | •                        |
| Peak On–State Voltage ( $I_{TM} = \pm .85$ A Peak; Pulse Width $\leq 2.0$ ms, Duty Cycle $\leq 2.0$ %)  | $V_{TM}$                            | -                | _                        | 1.9                      | Volts                    |
| Gate Trigger Current (Continuous dc) $(V_D=12\ \text{Vdc},\ R_L=100\ \text{Ohms})$ $MT2(+),\ G(+)$ $MT2(+),\ G(-)$ $MT2(-),\ G(-)$ $MT2(-),\ G(+)$                                    | Івт                                 | -<br>-<br>-<br>- | -<br>-<br>-<br>-         | 10<br>10<br>10<br>10     | mA                       |
| MT2(+), G(+) MZ(+), G(-) MT2(-), G(-) MT2(-), G(+) MT2(-), G(+)   |                                     | -<br>-<br>-      | -<br>-<br>-              | 5.0<br>5.0<br>5.0<br>7.0 |                          |
| Gate Trigger Voltage (Continuous dc) (V <sub>D</sub> = 12 Vdc, R <sub>L</sub> = 100 Ohms) MT2(+), G(+) All Types MT2(+), G(-) All Types MT2(-), G(-) All Types MT2(-), G(+) All Types | V <sub>GT</sub>                     | -<br>-<br>-<br>- | .66<br>.77<br>.84<br>.88 | 2.0<br>2.0<br>2.0<br>2.5 | Volts                    |
| Gate Non–Trigger Voltage $(V_D = 12 \text{ V, R}_L = 100 \text{ Ohms, T}_J = 110^{\circ}\text{C})$ All Four Quadrants   | $V_{GD}$                            | 0.1              | -                        | -                        | Volts                    |
| Holding Current (V <sub>D</sub> = 12 Vdc, Initiating Current = 200 mA, Gate Open)   | I <sub>H</sub>                      | -                | 1.5                      | 10                       | mA                       |
| Turn-On Time $(V_D = Rated V_{DRM}, I_{TM} = 1.0 \text{ A pk}, I_G = 25 \text{ mA})$  | t <sub>gt</sub>                     | -                | 2.0                      | -                        | μS                       |
| DYNAMIC CHARACTERISTICS   |                                     |                  |                          |                          |                          |
| Critical Rate—of–Rise of Commutation Voltage ( $V_D$ = Rated $V_{DRM}$ , $I_{TM}$ = .84 A, Commutating di/dt = .3 A/ms, Gate Unenergized, $T_C$ = 50°C)                               | dV/dt(c)                            | _                | 5.0                      | _                        | V/µs                     |
| Critical Rate of Rise of Off–State Voltage $(V_D = Rated\ V_{DRM},\ T_C = 110^{\circ}C,\ Gate\ Open,\ Exponential\ Waveform$  | dv/dt                               | -                | 25                       | -                        | V/μs                     |

## Voltage Current Characteristic of Triacs (Bidirectional Device)

| Symbol           | Parameter                                 |
|------------------|---|
| $V_{DRM}$        | Peak Repetitive Forward Off State Voltage |
| I <sub>DRM</sub> | Peak Forward Blocking Current             |
| $V_{RRM}$        | Peak Repetitive Reverse Off State Voltage |
| I <sub>RRM</sub> | Peak Reverse Blocking Current             |
| V <sub>TM</sub>  | Maximum On State Voltage                  |
| I <sub>H</sub>   | Holding Current                           |



#### **Quadrant Definitions for a Triac**



All polarities are referenced to MT1.

With in–phase signals (using standard AC lines) quadrants I and III are used.

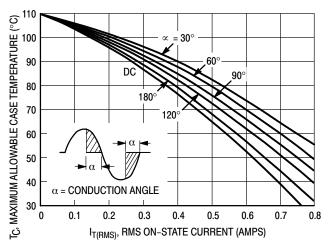


Figure 1. RMS Current Derating

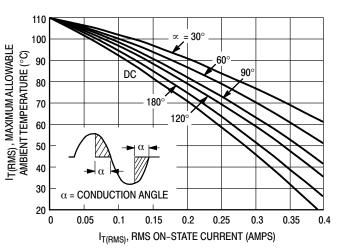


Figure 2. RMS Current Derating

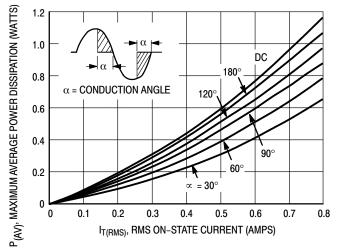


Figure 3. Power Dissipation

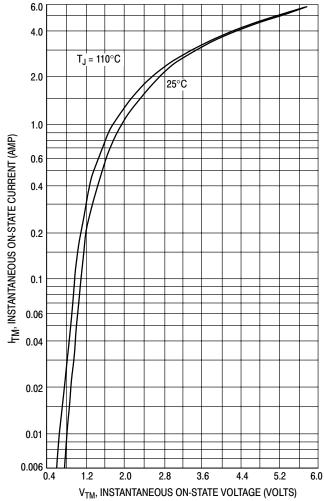


Figure 4. On-State Characteristics

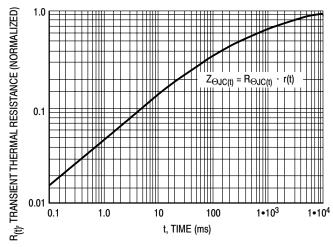
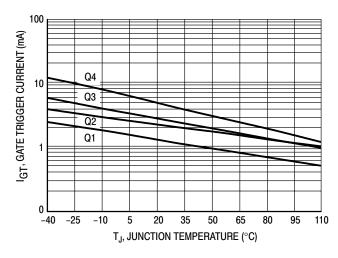


Figure 5. Transient Thermal Response

Figure 6. Maximum Allowable Surge Current



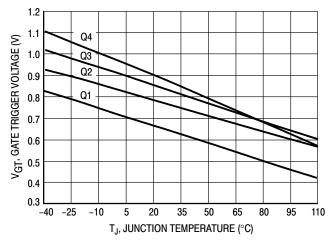
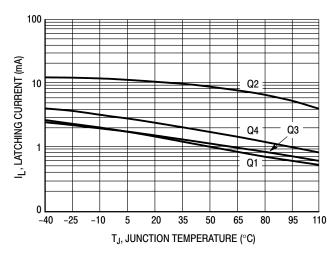


Figure 7. Typical Gate Trigger Current versus Junction Temperature

Figure 8. Typical Gate Trigger Voltage versus
Junction Temperature



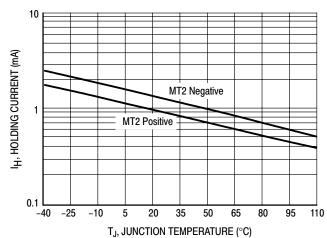


Figure 9. Typical Latching Current versus Junction Temperature

Figure 10. Typical Holding Current versus Junction Temperature

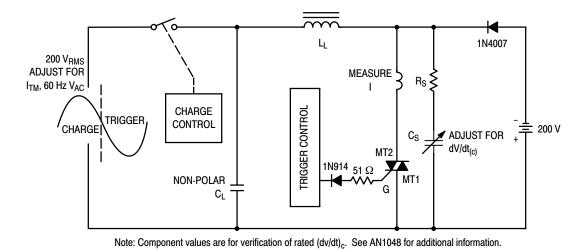


Figure 11. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Voltage  $(dV/dt)_c$ 

#### TO-92 EIA RADIAL TAPE IN FAN FOLD BOX OR ON REEL

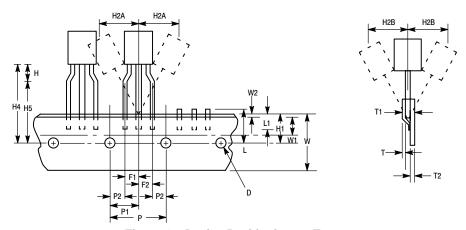


Figure 12. Device Positioning on Tape

|        |                                      |         | Specification |            |      |  |
|--------|--------------------------------------|---------|---------------|------------|------|--|
| Symbol | Item                                 | Inches  |               | Millimeter |      |  |
| Symbol | Item                                 | Min     | Max           | Min        | Max  |  |
| D      | Tape Feedhole Diameter               | 0.1496  | 0.1653        | 3.8        | 4.2  |  |
| D2     | Component Lead Thickness Dimension   | 0.015   | 0.020         | 0.38       | 0.51 |  |
| F1, F2 | Component Lead Pitch                 | 0.0945  | 0.110         | 2.4        | 2.8  |  |
| Н      | Bottom of Component to Seating Plane | .059    | 0.156         | 1.5        | 4.0  |  |
| H1     | Feedhole Location                    | 0.3346  | 0.3741        | 8.5        | 9.5  |  |
| H2A    | Deflection Left or Right             | 0       | 0.039         | 0          | 1.0  |  |
| H2B    | Deflection Front or Rear             | 0       | 0.051         | 0          | 1.0  |  |
| H4     | Feedhole to Bottom of Component      | 0.7086  | 0.768         | 18         | 19.5 |  |
| H5     | Feedhole to Seating Plane            | 0.610   | 0.649         | 15.5       | 16.5 |  |
| L      | Defective Unit Clipped Dimension     | 0.3346  | 0.433         | 8.5        | 11   |  |
| L1     | Lead Wire Enclosure                  | 0.09842 | -             | 2.5        | -    |  |
| Р      | Feedhole Pitch                       | 0.4921  | 0.5079        | 12.5       | 12.9 |  |
| P1     | Feedhole Center to Center Lead       | 0.2342  | 0.2658        | 5.95       | 6.75 |  |
| P2     | First Lead Spacing Dimension         | 0.1397  | 0.1556        | 3.55       | 3.95 |  |
| Т      | Adhesive Tape Thickness              | 0.06    | 0.08          | 0.15       | 0.20 |  |
| T1     | Overall Taped Package Thickness      | -       | 0.0567        | _          | 1.44 |  |
| T2     | Carrier Strip Thickness              | 0.014   | 0.027         | 0.35       | 0.65 |  |
| W      | Carrier Strip Width                  | 0.6889  | 0.7481        | 17.5       | 19   |  |
| W1     | Adhesive Tape Width                  | 0.2165  | 0.2841        | 5.5        | 6.3  |  |
| W2     | Adhesive Tape Position               | 0.0059  | 0.01968       | 0.15       | 0.5  |  |

- 2. Maximum alignment deviation between leads not to be greater than 0.2 mm.
- 3. Defective components shall be clipped from the carrier tape such that the remaining protrusion (L) does not exceed a maximum of 11 mm.
- 4. Component lead to tape adhesion must meet the pull test requirements.
- 5. Maximum non–cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
  6. Holddown tape not to extend beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.
- 7. No more than 1 consecutive missing component is permitted.8. A tape trailer and leader, having at least three feed holes is required before the first and after the last component.
- 9. Splices will not interfere with the sprocket feed holes.

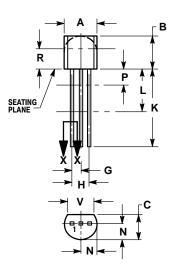
#### ORDERING & SHIPPING INFORMATION: MAC97 Series packaging options, Device Suffix

| U.S.                      | Europe<br>Equivalent | Shipping                              | Description of TO92 Tape Orientation                 |
|---------------------------|----------------------|---------------------------------------|--|
|                           | MAC97A6RL1, A8RL1    | Radial Tape and Reel (2K/Reel)        | Flat side of TO92 and adhesive tape visible          |
| MAC97–8,<br>MAC97A4,A6,A8 |                      | Bulk in Box (5K/Box)                  | N/A, Bulk  |
| MAC97A6RLRF               |                      | Radial Tape and Reel (2K/Reel)        | Round side of TO92 and adhesive tape on reverse side |
| MAC97A8RLRP               |                      | Radial Tape and Fan Fold Box (2K/Box) | Round side of TO92 and adhesive tape visible         |

#### **PACKAGE DIMENSIONS**

#### TO-92 (TO-226AA)

CASE 029-11 **ISSUE AL** 





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|     | INCHES |       | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN    | MAX   | MIN    | MAX    |
| Α   | 0.175  | 0.205 | 4.45   | 5.20   |
| В   | 0.170  | 0.210 | 4.32   | 5.33   |
| С   | 0.125  | 0.165 | 3.18   | 4.19   |
| D   | 0.016  | 0.021 | 0.407  | 0.533  |
| G   | 0.045  | 0.055 | 1.15   | 1.39   |
| Н   | 0.095  | 0.105 | 2.42   | 2.66   |
| J   | 0.015  | 0.020 | 0.39   | 0.50   |
| K   | 0.500  |       | 12.70  |        |
| L   | 0.250  |       | 6.35   |        |
| N   | 0.080  | 0.105 | 2.04   | 2.66   |
| Р   |        | 0.100 |        | 2.54   |
| R   | 0.115  |       | 2.93   |        |
| ٧   | 0.135  |       | 3.43   |        |

STYLE 12:
PIN 1. MAIN TERMINAL 1
2. GATE
3. MAIN TERMINAL 2





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